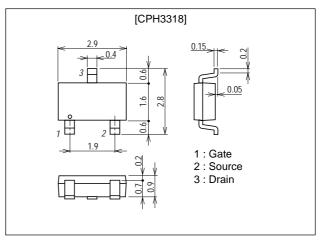


Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit : mm 2152A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-4	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-500mA	0.57	0.82		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-500mA, V _G S=-10V		420	550	mΩ
	R _{DS} (on)2	ID=-300mA, VGS=-4V		720	1000	mΩ

Marking: JT

- Any and all TY products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your TY representative nearest you before using any TY products described or contained herein in such applications.
- TY assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all TY products described or contained herein.